## RF \& MICROWAVE TRANSISTORS

 AVIONICS APPLICATIONS
## 

- 1025-1150 MHz
- GOLD METALLIZATION
- INPUT MATCHED
- INFINITE VSWR CAPABILITY @ RATED CONDITIONS
- Pout $=35$ W MINIMUM
- $G_{p}=10.7 \mathrm{~dB}$


## 

The MS2575 is a medium power Class C transistor designed specifically for pulsed L-Band avionics applications. Low RF thermal resistance and computerized automatic wire bonding techniques ensure high reliability and product consistency. The MS2575 is housed in the IMPAC ${ }^{\text {TM }}$ package with internal input matching.


## 

| Symbol | Parameter | Value | Unit |
| :---: | :---: | :---: | :---: |
| $\mathrm{P}_{\text {diss }}$ | Power Dissipation | 150 | W |
| $\mathrm{V}_{\text {CE }}$ | Collector-Emitter Bias Voltage | 55 | V |
| $\mathrm{T}_{J}$ | Junction Temperature | 200 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{I}_{\mathrm{c}}$ | Device Current | 3 | A |
| $\mathrm{T}_{\text {STG }}$ | Storage Temperature | -65 to +200 | ${ }^{\text {O }}$ C |

## ** 轎気

| $\mathbf{R}_{\mathrm{TH}(J-\mathrm{C})}$ | Junction-case Thermal Resistance | 1.0 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| :---: | :--- | :---: | :---: |

## MS2575

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| Svmbol | Test Conditions |  | Value |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | Min. | Tvp. | Max. | Unit |
| $\mathrm{BV}_{\text {cbo }}$ | $\mathrm{I}_{\mathrm{C}}=10 \mathrm{~mA}$ | $\mathrm{I}_{\mathrm{E}}=0 \mathrm{~mA}$ | 65 | --- | --- | V |
| $\mathrm{BV}_{\text {cER }}$ | $\mathrm{I}_{\mathrm{C}}=10 \mathrm{~mA}$ | $\mathrm{R}_{\text {BE }}=10 \Omega$ | 65 | --- | --- | V |
| $\mathrm{BV}_{\text {EBO }}$ | $\mathrm{I}_{\mathrm{E}}=1 \mathrm{~mA}$ | $\mathrm{I}_{\mathrm{C}}=0 \mathrm{~mA}$ | 3.5 | --- | --- | V |
| $\mathrm{I}_{\text {ces }}$ | $\mathrm{V}_{\text {CE }}=50 \mathrm{~V}$ |  | --- | --- | 5.0 | mA |
| HFE | $\mathrm{V}_{\mathrm{CE}}=5 \mathrm{~V}$ | $\mathrm{I}_{\mathrm{C}}=500 \mathrm{~mA}$ | 15 | --- | 120 | --- |





| FREQ | $\mathrm{Z}_{\mathrm{IN}}(\Omega)$ | $\mathrm{Z}_{\mathrm{cL}}(\Omega)$ |
| :---: | :---: | :---: |
| 1025 MHz | $2.6+\mathrm{j} 8.3$ | $7.7+\mathrm{j} 2.0$ |
| 1090 MHz | $2.8+\mathrm{j} 8.7$ | $7.1+\mathrm{j} 1.0$ |
| 1150 MHz | $3.2+\mathrm{j} 4.4$ | $6.5-\mathrm{j} 0.5$ |

Pin = 3W Vce $=50 \mathrm{~V}$

## 

## PACKAGE STYLEMT1S



|  | MINIMUM <br> INCHES/MM | MAXIMUM <br> INCHES/MM |  | MINIMUM <br> INCHES $/ M M$ | MAXIMUM <br> INCHES/MM |
| :---: | :---: | :---: | :---: | :---: | :---: |
| A | $.095 / 2,41$ | $.105 / 2,67$ |  |  |  |
| B | $.195 / 4,95$ | $.205 / 5,21$ |  |  |  |
| C | $1.000 / 25,40$ |  |  |  |  |
| D | $.004 / 0,10$ | $.007 / 0,18$ |  |  |  |
| E | $.050 / 1,27$ | $.065 / 1,65$ |  |  |  |
| F | $.120 / 3,05$ | $.135 / 3,43$ |  |  |  |
| G | $.275 / 6,99$ | $.285 / 7,21$ |  |  |  |
|  |  |  |  |  |  |

